

## FEATURES

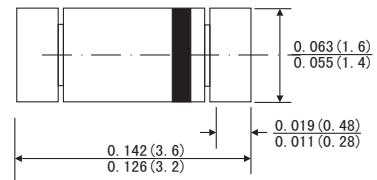
- For general purpose applications
- These diodes features very low turn-on voltage and fast switching
- These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges.
- This diode is also available in the DO-35 case with type designation BAT48.
- High temperature soldering guaranteed: 260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU

## MECHANICAL DATA

- Case: MiniMELF glass case(SOD-80)
- Weight: Approx. 0.05 gram

## ABSOLUTE RATINGS(LIMITING VALUES)

Dimensions in inches and (millimeters)



|  | Symbols          | Value             | Units |
|--|------------------|-------------------|-------|
| Repetitive Peak Reverse Voltage  | V <sub>RRM</sub> | 40                | V     |
| Forward Continuous Current at T <sub>A</sub> =25°C                                 | I <sub>F</sub>   | 350 <sup>1)</sup> | mA    |
| Repetitive Peak Forward Current at t <sub>p</sub> <1s, δ<0.5, T <sub>A</sub> =25°C | I <sub>FRM</sub> | 1 <sup>1)</sup>   | A     |
| Surge forward current at t <sub>p</sub> <10ms, T <sub>A</sub> =25°C                | I <sub>FSM</sub> | 7.5 <sup>1)</sup> | A     |
| Power Dissipation at T <sub>A</sub> =65°C  | P <sub>tot</sub> | 330 <sup>1)</sup> | mW    |
| Junction temperature   | T <sub>J</sub>   | 125               | °C    |
| Ambient Operating temperature Range  | T <sub>A</sub>   | -65 to+125        | °C    |
| Storage Temperature Range  | T <sub>STG</sub> | -65 to+150        | °C    |

1) Valid provided that electrodes are kept at ambient temperature

## ELECTRICAL CHARACTERISTICS

|   | Symbols  | Min. | Typ. | Max.                           | Units                            |
|---|--|------|------|--------------------------------|----------------------------------|
| Reverse Breakdown Voltage Tested with 100μA Pulses  | V <sub>(BR)R</sub>   | 40   |      |                                | V                                |
| Forward voltage<br>Pulse Test t <sub>p</sub> <300μs, δ<2%<br>at I <sub>f</sub> =0.1mA,<br>at I <sub>f</sub> =10mA,<br>at I <sub>f</sub> =250mA  | V <sub>F</sub><br>V <sub>F</sub><br>V <sub>F</sub>   |      |      | 0.25<br>0.45<br>0.90           | V                                |
| Leakage current<br>pulse test t <sub>p</sub> <300μs, δ<2%<br>at V <sub>R</sub> =10V<br>at V <sub>R</sub> =10V, T <sub>J</sub> =60°C<br>at V <sub>R</sub> =20V<br>at V <sub>R</sub> =20V, T <sub>J</sub> =60°C<br>at V <sub>R</sub> =40V<br>at V <sub>R</sub> =40V, T <sub>J</sub> =60°C | I <sub>R</sub><br>I <sub>R</sub><br>I <sub>R</sub><br>I <sub>R</sub><br>I <sub>R</sub><br>I <sub>R</sub> |      |      | 2<br>15<br>5<br>25<br>25<br>50 | μA<br>μA<br>μA<br>μA<br>μA<br>μA |
| Junction Capacitance at V <sub>R</sub> =1V, f=1MHz  | C <sub>J</sub>   |      | 2    |                                | pF                               |
| Thermal resistance junction to ambient Air  | R <sub>θJA</sub>   |      |      | 300 <sup>1)</sup>              | °C/W                             |

1) Valid provided that electrodes are kept at ambient temperature

## RATINGS AND CHARACTERISTIC CURVES LL48

Figure 1. Forward current versus forward voltage at different temperatures(typical values)

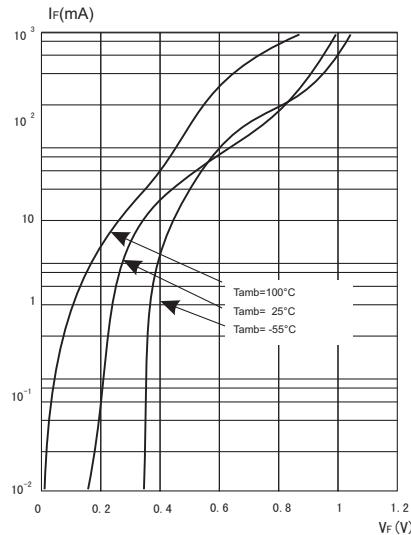


Figure 2. Forward current versus forward voltage (typical values)

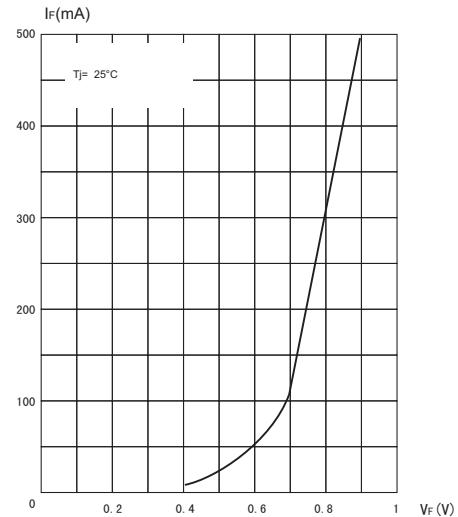
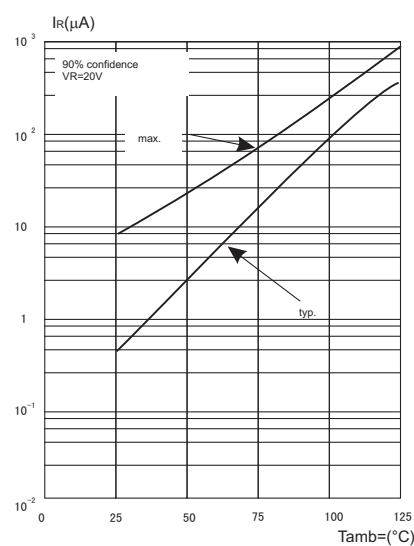


Figure 3.Reverse current versus ambient temperatures



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Figure 4.Reverse current versus continuous  
Reverse voltage(typical values)

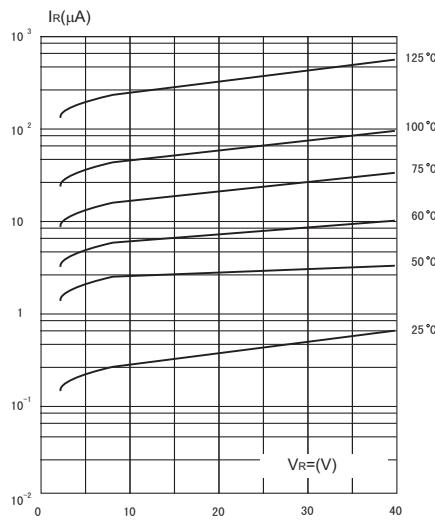


Figure 5.Capacitance CJ versus reverse applied  
voltage VR (typical values)

